

# 2SC5051

# Silicon NPN Epitaxial

REJ03G0741-0300 (Previous ADE-208-1131A) Rev.3.00 Aug.10.2005

## **Application**

VHF / UHF wide band amplifier

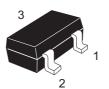
### **Features**

• High gain bandwidth product  $f_T = 11 \text{ GHz Typ}$ 

• High gain, low noise figure PG = 14.5 dB Typ, NF = 1.1 dB Typ at f = 900 MHz

## **Outline**

RENESAS Package code: PTSP0003ZA-A (Package name: CMPAK  $^{\circledR}$ )



1. Emitter

2. Base

3. Collector

Note: Marking is "YZ-".

\*CMPAK is a trademark of Renesas Technology Corp.

Attention: This device is very sensitive to electro static discharge.

It is recommended to adopt appropriate cautions when handling this transistor.

## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

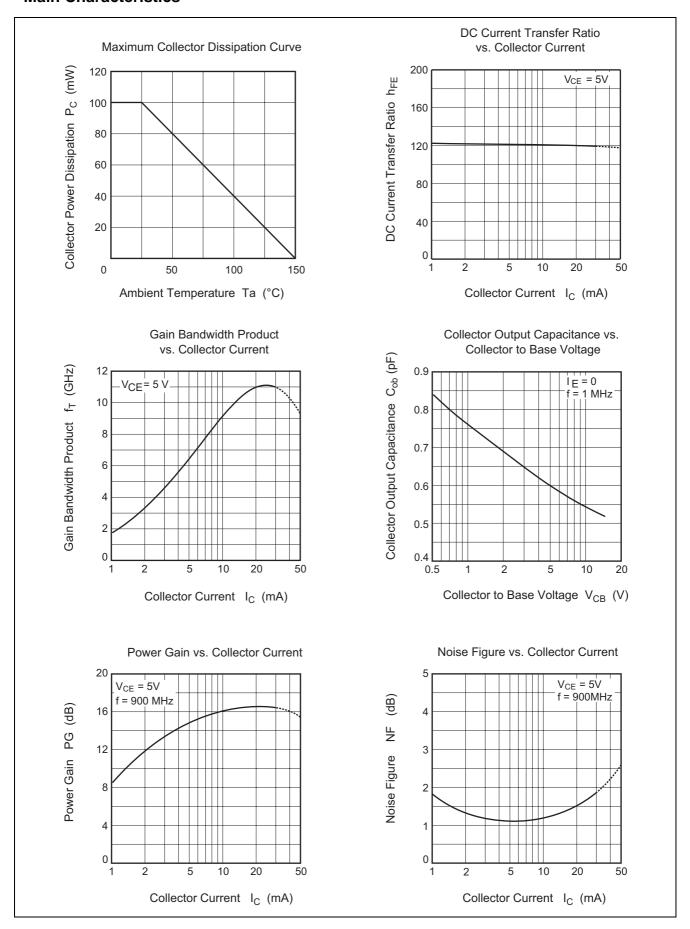
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	15	V
Collector to emitter voltage	$V_{\sf CEO}$	8	V
Emitter to base voltage	$V_{EBO}$	1.5	V
Collector current	Ic	50	mA
Collector power dissipation	Pc	100	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

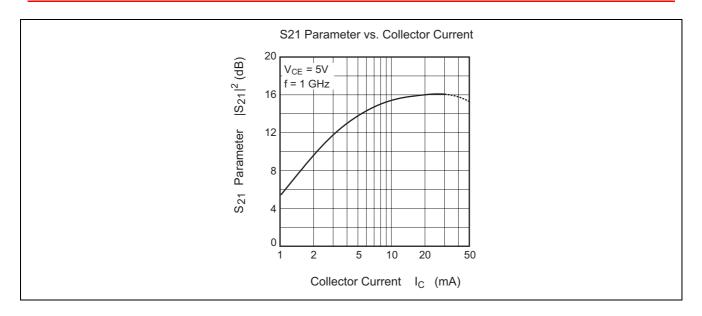
# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

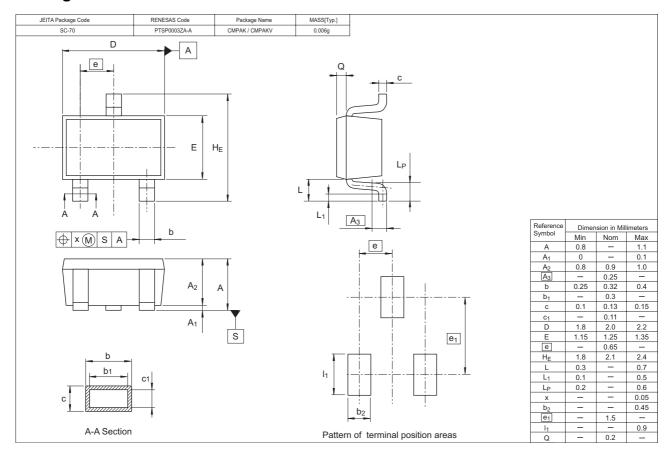
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector cutoff current	I <sub>CBO</sub>		_	10	μΑ	$V_{CB} = 12 \text{ V}, I_{E} = 0$
	I <sub>CEO</sub>		_	1	mA	V <sub>CE</sub> = 8 V, R <sub>BE</sub> = ∞
Emitter cutoff current	I <sub>EBO</sub>		_	10	μΑ	$V_{EB} = 1.5 \text{ V}, I_C = 0$
DC current transfer ratio	h <sub>FE</sub>	50	120	250		$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Collector output capacitance	Cob		0.65	1.15	pF	$V_{CB} = 5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f⊤	8.0	11.0	_	GHz	$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}$
S21 Parameter	$ S_{21} ^2$		14.0	_	dB	$V_{CE} = 5 \text{ V, } I_{C} = 20 \text{ mA,}$ f = 1000 MHz
Power gain	PG	11.5	14.5	_	dB	$V_{CE} = 5 \text{ V, } I_{C} = 20 \text{ mA,}$ f = 900 MHz
Noise figure	NF	_	1.1	2.0	dB	$V_{CE} = 5 \text{ V, } I_{C} = 5 \text{ mA,}$ f = 900 MHz

## **Main Characteristics**





# **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
2SC5051YZ-TR-E	3000	φ 178 mm Reel, 8 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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